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Vishay Semiconductors

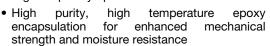
High Performance Schottky Rectifier, 2 x 10 A



PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 10 A							
V _R	35 V, 45 V							
V _F at I _F	0.57 V							
I _{RM} max.	15 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	8 mJ							
Package	3L TO-220AB							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_{.1} operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform (per device)	20	Α					
V _{RRM}		35/45	V					
I _{FRM}	T _C = 135 °C (per leg)	20	Δ.					
I _{FSM}	t _p = 5 μs sine	1060	Α					
V _F	10 A _{pk} , T _J = 125 °C	0.57	V					
T _J	Range	-65 to +150	°C					

VOLTAGE RATINGS								
PARAMETER SYMBOL VS-MBR2035CT-M3 VS-MBR2045CT-M3 UNI								
Maximum DC reverse voltage	V_R	35	45	V				
Maximum working peak reverse voltage	V _{RWM}	35	45	v 				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS					
Maximum average forward per leg		T 125 °C rotod V		10				
current per device	I _{F(AV)}	$T_C = 135$ °C, rated V_R		20	ļ			
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 k	Hz, T _C = 135 °C	20				
Non-repetitive peak surge current	I _{ESM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060	А			
3	1 GIVI	Surge applied at rated load c single phase, 60 Hz	150					
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to z Frequency limited by T _J max	2					
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 4 \text{m}$	8	mJ				

Revision: 18-Aug-17 1 Document Number: 96283



VS-MBR2035CT-M3, VS-MBR2045CT-M3

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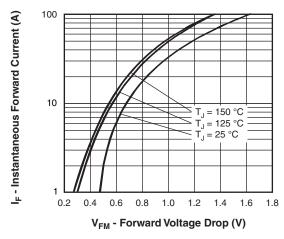
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		20 A	T _J = 25 °C	0.84				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	10 A	T _{.I} = 125 °C	0.57	V			
		20 A	1j = 125 C	0.72				
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mΛ			
waxiinum instantaneous reverse current	IRM (")	T _J = 125 °C	hated DC voltage	15	mA			
Threshold voltage	V _{F(TO)}	$T_{.1} = T_{.1}$ maximum		0.354	V			
Forward slope resistance	r _t	rj = rjinaximum		17.6	mΩ			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	600	pF				
Typical series inductance	L _S	Measured from top of term	8.0	nΗ				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ		-65 to +150	°C				
Maximum storage temperature range	T _{Stg}		-65 to +175					
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	2.0	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (only for TO-220)	0.50	C/VV				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Mounting torque minimum	n	Non-lubricated threads	6 (5)	kgf · cm (lbf · in)				
Mounting torque maximum		Non-lubricated tilleads	12 (10)					
Modeina device		Coop ot do 21 TO 200AP	MBR2035CT					
Marking device		Case style 3L TO-220AB		MBR2045CT				

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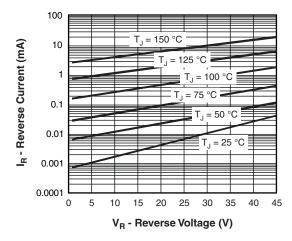


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

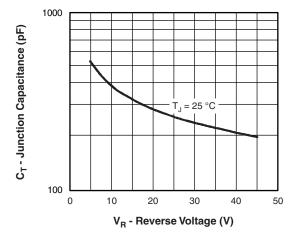


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

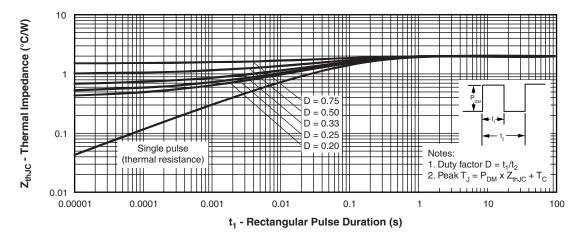


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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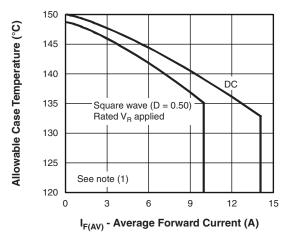


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

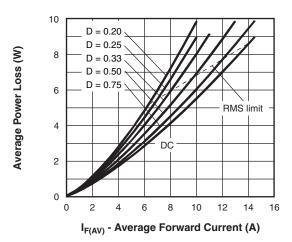


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

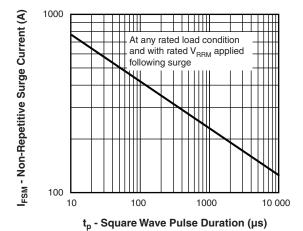


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

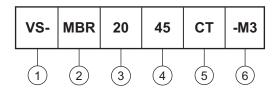
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = rated V_R

VS-MBR2035CT-M3, VS-MBR2045CT-M3

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

- Current rating (20 = 20 A)

35 = 35 V 45 = 45 V

CT = essential part numberEnvironmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-MBR2035CT-M3	50	1000	Antistatic plastic tube						
VS-MBR2045CT-M3	50	1000	Antistatic plastic tube						

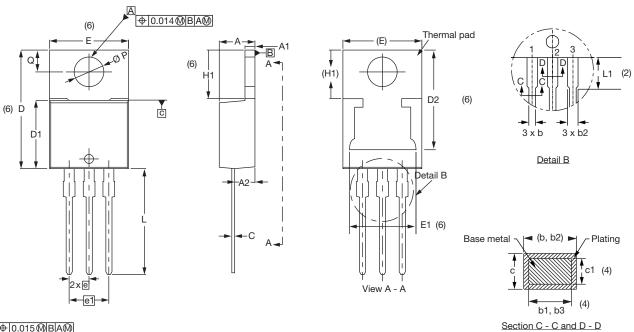
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						
SPICE model	www.vishay.com/doc?95295						



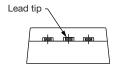
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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INCHES		SYMBOL	MILLIMETERS		INCHES		NOTES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355								

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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